

PNP Silicon Transistor

Applications

- Power amplifier application
- High current switching application

Features

- Low saturation voltage:
- $V_{CE(sat)}$ =-0.15V Typ. @ I_C=-1A, I_B=-50mA
- Large collector current capacity: I_C =-3A
- Small and compact SMD type package
- "Green" device and RoHS compliant device
- Available in full lead (Pb)-free device

Ordering Information

Type NO.	Marking	Package Code
STA3350Q	STA3350 YWW	SOT-223

STA3350: DEVICE CODE, YWW(Y : Year code, WW : Weekly code)

Absolute Maximum Ratings

Absolute Maximum Katings [1a-2				
Characteristic	Symbol	Rating	Unit	
Collector-base voltage	V _{CBO}	-50	V	
Collector-emitter voltage	V _{CEO}	-50	V	
Emitter-base voltage	V _{EBO}	-6	V	
	I _C	-3	A(DC)	
Collector current	I _{CP} *	-6	A(Pulse)	
Collector Down dissinction	P _C	1.1	W	
Collector Power dissipation	P _c **	-50 V -50 V -6 V -3 A(DC -6 A(Puls	W	
Junction temperature	T ₃	150	°C	
Storage temperature range	T _{stg}	-55~150	°C	

*: Single pulse, tp= $300 \ \mu s$

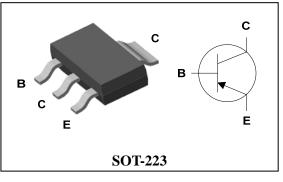
** : When mounted on copper substrate(250 $mm^2 \times 0.8t$)

Characteristic		Symbol	Тур.	Мах	Unit
Thermal resistance	Junction-ambient	R _{th(J-a)}	-	113.6	°C/W
			-	83.3**	°C/W



[Ta=25℃]

PIN Connection

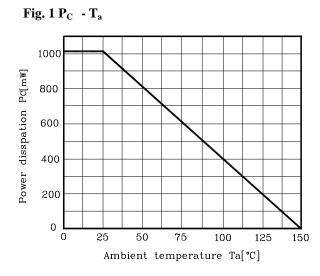


Electrical Characteristics

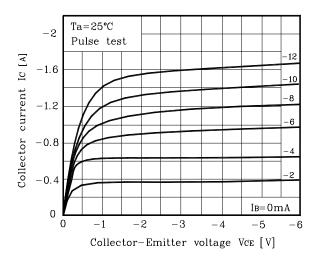
Electrical Characteristics [Ta=25						= 25℃]		
Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit	
Collector-emitter	breakdown voltage	BV _{CEO}	I _C =-1mA, I _B =0	-50 -		-	V	
Collector cut-off c	urrent	I _{CBO}	V _{CB} =-50V, I _E =0	-	-	-1	μA	
Emitter cut-off cu	rrent	I _{EBO}	V _{EB} =-6V, I _C =0	-	-	-1	μA	
		h _{FE}	V _{CE} =-2V, I _C =-0.5A*	120	-	240		
DC current gain	DC current gain		V _{CE} =-2V, I _C =-2A*	40	-	-		
Collector-emitter	ector-emitter saturation voltage		I _C =-1A, I _B =-0.05A*	-	-	-0.35	V	
Base-emitter satu	ration voltage	$V_{BE(sat)}$	I _C =-2A, I _B =-0.1A*	0.97 -1		-1.2	V	
Transition frequen	nsition frequency		V _{CE} =-10V, I _C =-0.05A	-	250	-	MHz	
Collector output capacitance		C _{ob}	V_{CB} =-10V, I_E =0, f=1MHz	-	28	-	pF	
Switching Time	Turn-on Time	t _{on}	$I_{BI} \xrightarrow{I_{BE}} INPUT \xrightarrow{I_{BE}} OUTPUT$ $I_{III} \xrightarrow{I_{BE}} 30$ $-I_{IIII} = IBE=100 \text{ mA} - 30 \text{ V}$ $DUTY CYCLE \leq 1\%$	-	100	-		
	Storage Time	t _{stg}		-	300	-	ns	
	Fall Time	t _f		-	50	-		

*: Pulse test : $t_{P}{\leq}300\mu s,$ Duty cycle ${\leq}2\%$

Electrical Characteristic Curves









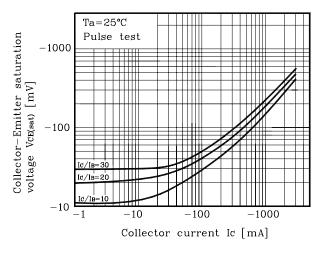


Fig. 2 $I_C\;$ - V_{BE}

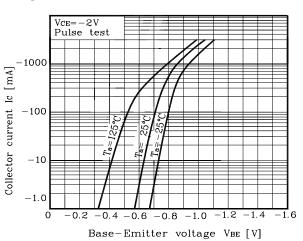
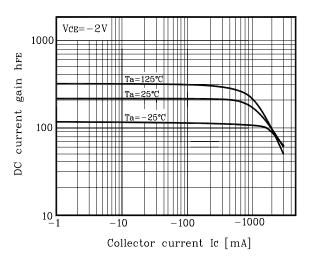
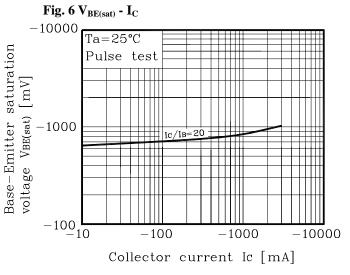
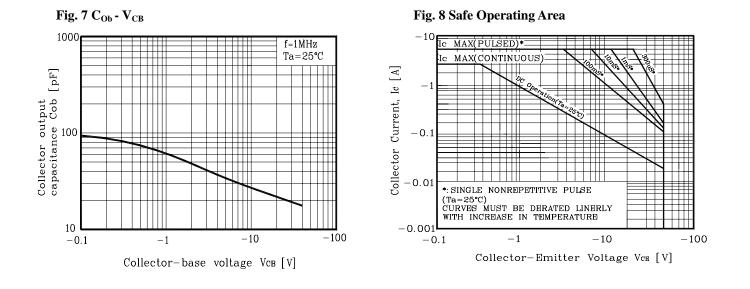


Fig. 4 h_{FE} - I_C

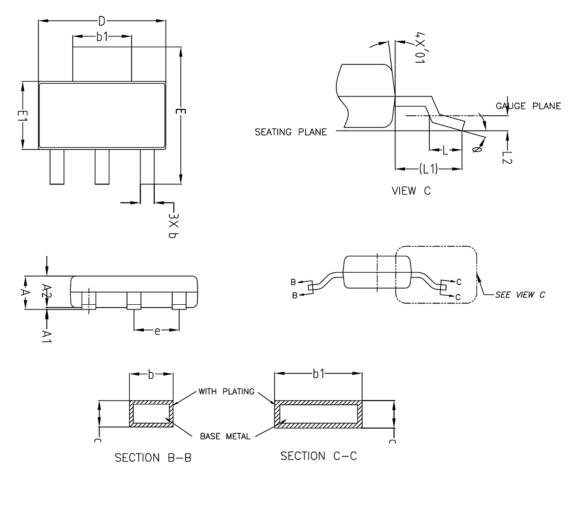




Electrical Characteristic Curves

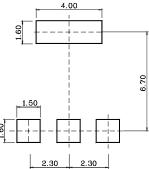


Outline Dimension



	MILLIMETERS			
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	NOTE
Α	-	-	1.80	
A1	0.00	-	0.10	
A2	1.60	1.65	1.70	
b	0.68	-	0.76	
b1	2.95	-	3.07	
с	0.23	-	0.28	
D	6.40	6.50	6.60	
E	6.80	7.00	7.20	
E1	3.40	3.50	3.60	
е		2.30 BSC		
L	0.45	-	0.65	
L1	1.75 REF			
L2	0.10 BSC			
θ	0.	-	10'	
0 1	5'	-	10*	

* Recommend PCB solder land [Unit: mm]



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